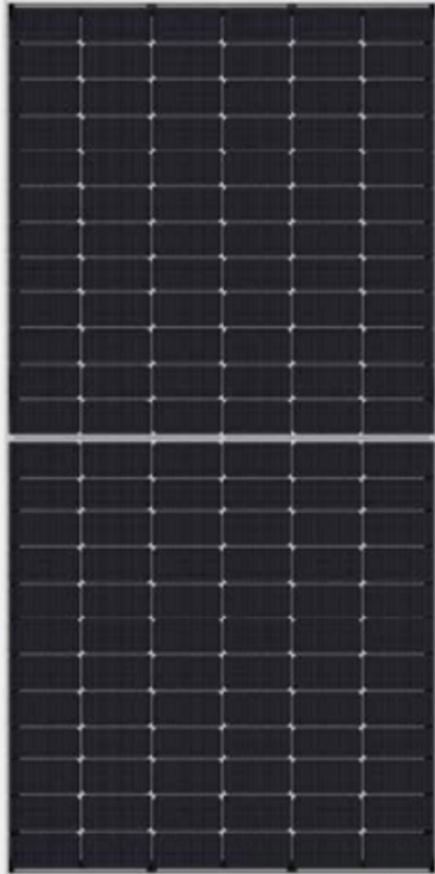


**NEW**

T-610M72



## N-TOPCon Technology

### 22.65%

Maximum Conversion Efficiency

### 610W

Maximum Power of Component

### 2278×1134×30mm

Component dimensions

IEC 61215 / IEC 61730  
ISO 9001: Quality Management System  
ISO 14001: Environmental Management System

**0-±3%**

Output power is guaranteed to be within a positive tolerance of 0-3%

**Lower Electricity Cost**

High-quality silicon wafer guarantee, high-power component output, and excellent cost-performance advantages make it the ideal choice for large-scale power stations.

**Strict Quality Control**

3 times EL test, ensure the best quality

## Technical Parameters

### Product Specifications

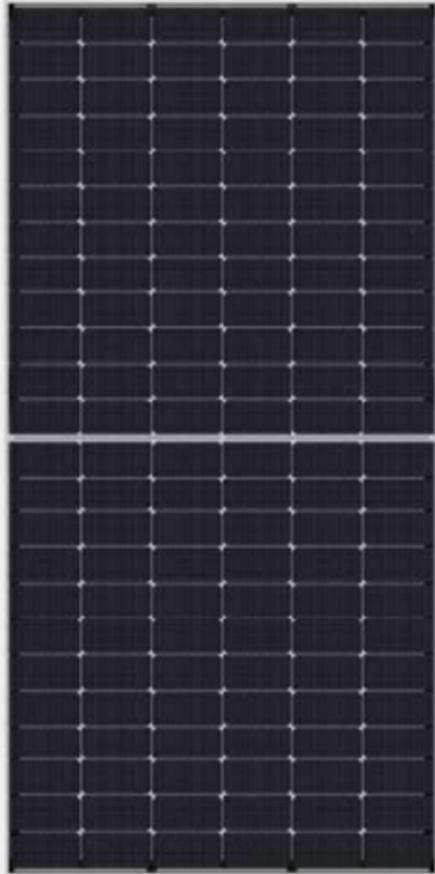
Cell type	N-type monocrystalline silicon cell
Cell sheet size	182×182mm
Half-cell battery quantity	144(2×72)
Component weight	28kg(±3%)
Component dimensions	2278×1134×30mm
Output wire	4.0mm Positive: 300mm Negative: 300mm, cable length customizable
Upper surface glass material	3.2mm high-transmittance, coated tempered glass
Frame	Anodized aluminum alloy
Junction box	Protection Grade IP68
Connector type	MC4 compatible connector
Mechanical load	Front: 5400Pa/Back: 2400Pa

### Working Conditions

Maximum system voltage (M)	1000/1500VDC (IEC)
Maximum power temperature coefficient (Pmax)	-0.30%/°C
Open circuit voltage temperature coefficient (Voc)	-0.25%/°C
Open circuit Voltage temperature coefficient (Isc)	0.046%/°C
Rated operating cell temperature	45±2°C
Operating temperature range	-40°C to +85°C
Maximum rated current of the fuse wire	25A

**NEW**

T-610M72



## N-TOPCon Technology

### 22.65%

Maximum Conversion Efficiency

### 610W

Maximum Power of Component

### 2278×1134×30mm

Component dimensions

12 years material and process warranty  
30 years linear warranty

### Fusion Half-Cut Multi-Busbar Technology

New circuit design, reducing the impact of shadowing on the power generation performance of components to the lowest, optimizing light utilization rate and current collection capability, effectively enhancing product power output and reliability

### Outstanding PID Resistance

Guarantee mass production through PID test, significantly reduce the attenuation caused by PID through optimizing battery process

### Excellent Low Light Performance

Using high-transmittance coated glass and velvetizing technology on the surface of the battery cells to achieve excellent performance in low-light environments

## Technical Parameters

### Electrical Performance Parameters | STC

Maximum power (Pmax) [W]	585	590	595	600
Maximum power point operating voltage (Vmp) [V]	42.52	42.67	42.82	42.97
Maximum power point operating current (Imp) [A]	13.76	13.83	13.90	13.97
Open circuit voltage (Voc) [V]	51.16	51.30	51.44	51.58
Short-circuit current (Isc) [A]	14.55	14.63	14.71	14.79
Component efficiency [%]	22.65	22.85	23.05	23.25

STC: Light intensity 1000W/m<sup>2</sup> module temperature 25°C AM=1.5

### Electrical Performance Parameters | NOCT

Maximum power (Pmax) [W]	565	570	575	580
Maximum power point operating voltage (Vmp) [V]	41.92	42.07	42.22	42.37
Operating current at maximum power point (Imp) [A]	13.48	13.55	13.62	13.69
Open circuit voltage (Voc) [V]	50.60	50.74	50.88	51.02
Short-circuit current (Isc) [A]	14.23	14.31	14.39	14.47

NOCT: Light intensity 800W/m<sup>2</sup> module temperature 20°C wind speed: 1m/s

### Packaging Method

Per pallet quantity 36 pieces per pallet

17.5m flatbed truck loading capacity 1008 pieces